Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Ceramic and metal
Overall Length:
1.253 inches
Overall Width:
0.500 inches
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-4
Electrode Internally-electrically Connected To Case:
Cathode
Mounting Method:
Threaded stud
Thready Qty Per Inch (tpi):
32
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
600.0 repetitive peak reverse voltage and 720.0 nonrepetitive peak reverse voltage
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 1 wire hook
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0